

# **BY396 THRU BY399**

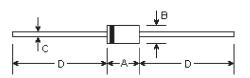
#### FAST RECOVERY SILICON RECTIFIER Reverse Voltage - 100 to 800 Volts

DO-201AD

Forward Current - 3.0 Amperes

#### Features

- Fast recovery diodes
- Diffused junction
- High surge capability
- The plastic material carries U/L recognition 94V-0
- Terminals: Axial leads
- Polarity: Color band denotes cathode



### **Mounting Instruction**

- Min. distance from body to soldering point, 4mm
- Max. solder temperature, 350 °C
- Max. soldering time: 3.5 Sec.
- Do not bend lead at a point closer than 3mm to the body
- Weight: 0.042 ounce, 1.195 gram

DIMENSIONS									
DIM	inches		m	Note					
	Min.	Max.	Min.	Max.	NOLE				
А	0.283	0.374	7.20	9.50					
В	0.189	0.208	4.80	5.30	ф				
С	0.048	0.051	1.20	1.30	ф				
D	1.000	-	25.40	-					

## **Maximum Ratings and Electrical Characteristics**

Ratings at 25  $^\circ\!\!\!\!^\circ C$  ambient temperature unless otherwise specified.

	Symbols	BY396	BY397	BY398	BY399	Units
Peak repetitive and non repetitive reverse voltage	V <sub>RRM</sub>	100	200	400	800	Volts
Forward current, R load at $\rm T_{amb}=50^\circ\!C$	I <sub>(AV)</sub>		Amps			
8.3mS peak forward surge current at $T_j {=} 25 {\rm °C}$	I <sub>FSM</sub>		Amps			
Recurrent peak forward current (A)	I		Amps			
Maximum forward voltage drop at $I_{\rm F}$ =3.0A	V <sub>F</sub>		Volts			
Maximum reverse current at $V_{_{\rm RRM}}$ at $25^\circ\!{\rm C}$	I <sub>R</sub>	10.0				μA
Maximum reverse recovery time (Note 1)	T"		nS			
Maximum thermal resistance (I=10mm)	R <sub>⊕JA</sub>	30.0				°C/W
Operating and storage temperature range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +125				°C

Note:

(1) Reverse recovery test conditions:  $I_{\rm F}$ =0.5A,  $I_{\rm R}$ =1.0A,  $I_{\rm m}$ =0.25A

